



### P-CHANNEL ENHANCEMENT MODE MOSFET

### **Product Summary**

V <sub>(BR)DSS</sub>	R <sub>DS(ON) max</sub>	Package	I <sub>D</sub> T <sub>A</sub> = +25°C	
-25V	27mΩ @ $V_{GS} = -4.5V$	U-DFN2020-6	-6.7A	
-25V	40mΩ @ V <sub>GS</sub> = -1.8V	Type E	-5.4A	

### **Description**

This new generation MOSFET has been designed to minimize the onstate resistance ( $R_{DS(on)}$ ) and yet maintain superior switching performance, making it ideal for high efficiency power management applications.

### **Applications**

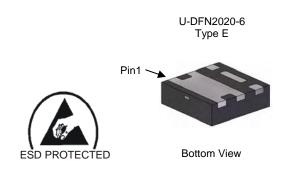
- Load Switching
- Battery Management Application
- Power Management Functions

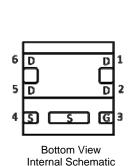
### **Features**

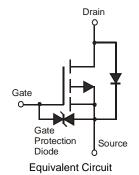
- Low R<sub>DS(ON)</sub> Ensures on State Losses are Minimized
- 0.6mm Profile Ideal for Low Profile Applications
- PCB Footprint of 4mm<sup>2</sup>
- ESD Protected Gate
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

### **Mechanical Data**

- Case: U-DFN2020-6 Type E
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Connections: See Diagram
- Weight: 0.001 grams (approximate)







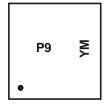
## Ordering Information (Note 4)

Part Number	Case	Packaging	
DMP2039UFDE-7	U-DFN2020-6 Type E	3,000/Tape & Reel	

Notes:

- 1. EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant. All applicable RoHS exemptions applied.
- 2. See http://www.diodes.com for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at http://www.diodes.com.

# **Marking Information**



P9 = Product Type Marking Code YM = Date Code Marking Y = Year (ex: Y = 2011) M = Month (ex: 9 = September)

Date Code Key

Year	201	1	2012		2013	20	14	2015		2016	2	2017
Code	Υ		Z		Α		3	С		D		Е
Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	0	N	D



# **Maximum Ratings** $(@T_A = +25^{\circ}C, \text{ unless otherwise specified.})$

Characteristic	Symbol	Value	Units		
Drain-Source Voltage	V <sub>DSS</sub>	-25	V		
Gate-Source Voltage			V <sub>GSS</sub>	±8	V
Continuous Durin Courset (Note 5) V	Steady State	, I		-6.7 -5.3	А
Continuous Drain Current (Note 5) V <sub>GS</sub> = -4.5V	t<5s	$T_A = +25$ °C $T_A = +70$ °C	I <sub>D</sub>	-8.3 -6.6	А
Steady $T_A = +2$ State $T_A = +7$			I <sub>D</sub>	-5.4 -4.3	А
Continuous Drain Current (Note 5) V <sub>GS</sub> = -1.8V	I <sub>D</sub>	-6.6 -5.2	А		
Pulsed Drain Current (10µs pulse, duty cycle = 1%)	I <sub>DM</sub>	-60	Α		
Continuous Source-Drain Diode Current	Is	-2.0	Α		

### **Thermal Characteristics**

Characteristic		Symbol	Value	Units	
Total Dawer Dissination (Note 5)	T <sub>A</sub> = +25°C	_	0.8	W	
Total Power Dissipation (Note 5)	T <sub>A</sub> = +70°C	$P_{D}$	1.2	VV	
Thermal Desigtance Junction to Ambient (Note 5)	Steady state	<u> </u>	160	°C // //	
Thermal Resistance, Junction to Ambient (Note 5)	t<5s	$R_{\theta JA}$	104	°C/W	
Total Dawar Dissination (Note C)	T <sub>A</sub> = +25°C		2.0	W	
Total Power Dissipation (Note 6)	T <sub>A</sub> = +70°C	$P_{D}$	2.9		
Thermal Desistance Junction to Ambient (Note 6)	Steady state		63	°C/W	
Thermal Resistance, Junction to Ambient (Note 6)	t<5s	$R_{\theta JA}$	42	· C/VV	
Thermal Resistance, Junction to Case (Note 6)	Steady state	$R_{ heta JC}$	10.8	°C/W	
Operating and Storage Temperature Range		T <sub>J,</sub> T <sub>STG</sub>	-55 to +150	°C	

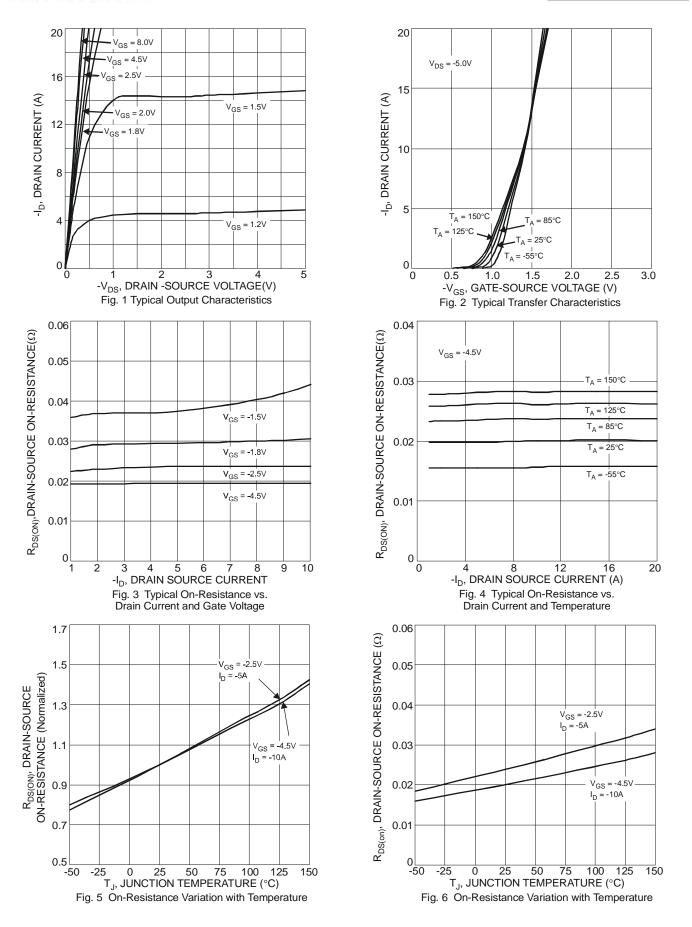
## Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 7)							
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	-25	_	_	V	$V_{GS} = 0V, I_D = -250\mu A$	
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	_	_	-1	μΑ	$V_{DS} = -25V, V_{GS} = 0V$	
Gate-Source Leakage	I <sub>GSS</sub>	_	_	±10	μA	$V_{GS} = \pm 8.0 V, V_{DS} = 0 V$	
ON CHARACTERISTICS (Note 7)							
Gate Threshold Voltage	V <sub>GS(th)</sub>	-0.4	_	-1.0	V	$V_{DS} = V_{GS}, I_{D} = -250 \mu A$	
		_	20	27		$V_{GS} = -4.5V$ , $I_D = -6.4A$	
Static Drain-Source On-Resistance	<b>D</b>	_	24	34		$V_{GS} = -2.5V, I_D = -4.8A$	
Static Drain-Source On-Resistance	R <sub>DS (ON)</sub>	_	28	40	mΩ	$V_{GS} = -1.8V, I_D = -2.5A$	
		_	33	70		$V_{GS} = -1.5V, I_D = -1.5A$	
Forward Transfer Admittance	Y <sub>fs</sub>	_	16	_	S	$V_{DS} = -5V, I_{D} = -4A$	
Diode Forward Voltage	V <sub>SD</sub>	_	-0.7	-1.0	V	$V_{GS} = 0V, I_{S} = -1A$	
DYNAMIC CHARACTERISTICS (Note 8)			•	•	•		
Input Capacitance	Ciss	_	2530	_	pF	45)/ )/ 0)/	
Output Capacitance	Coss	_	203	_	pF	$V_{DS} = -15V, V_{GS} = 0V$ -f = 1.0MHz	
Reverse Transfer Capacitance	Crss	_	177	_	pF	1 = 1.0lvin2	
Gate Resistance	$R_g$	_	9.1	_	Ω	$V_{DS} = 0V, V_{GS} = 0V, f = 1.0MHz$	
Total Gate Charge (V <sub>GS</sub> = -4.5V)	Qg	_	28.2	_	nC		
Total Gate Charge (V <sub>GS</sub> = -8V	Qq	_	48.7	_	nC	1, 45, 40,	
Gate-Source Charge	Q <sub>gs</sub>	_	3.2	_	nC	$V_{DS} = -15V, I_{D} = -4.0A$	
Gate-Drain Charge	$Q_{qd}$	_	5.0	_	nC	1	
Turn-On Delay Time	t <sub>D(on)</sub>	_	15.1	_	ns		
Turn-On Rise Time	t <sub>r</sub>	_	23.5	_	ns	$V_{DD} = -15V, V_{GS} = -4.5V, R_{G} = 1\Omega,$	
Turn-Off Delay Time	t <sub>D(off)</sub>	_	137.6	_	ns	I <sub>D</sub> = -4.0A	
Turn-Off Fall Time	t <sub>f</sub>	_	80.5	_	ns	1	

Notes:

Device mounted on FR-4 PC board, with minimum recommended pad layout, single sided.
 Device mounted on FR-4 substrate PC board, 2oz copper, with thermal bias to bottom layer 1inch square copper plate
 Short duration pulse test used to minimize self-heating effect
 Guaranteed by design. Not subject to production testing.







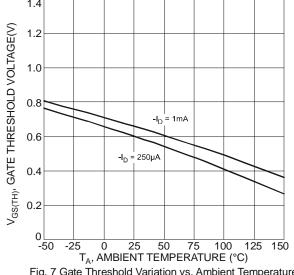
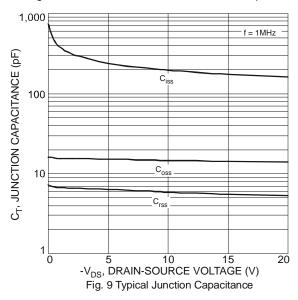
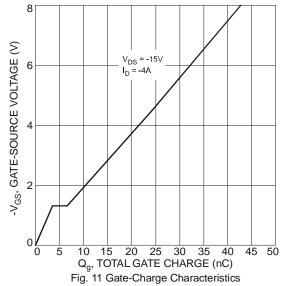
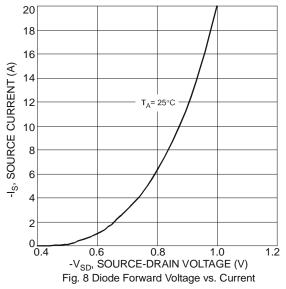


Fig. 7 Gate Threshold Variation vs. Ambient Temperature







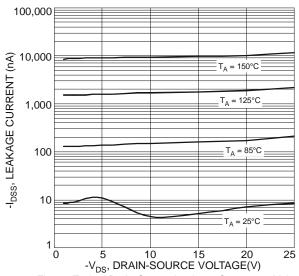
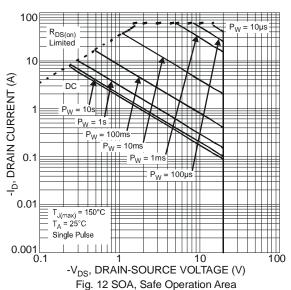
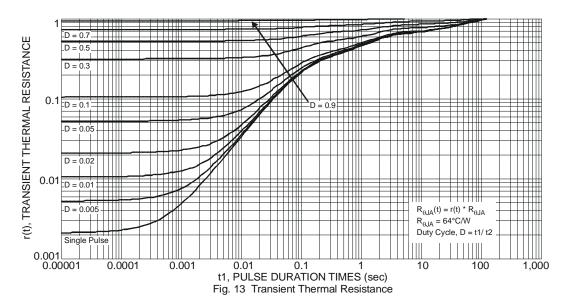


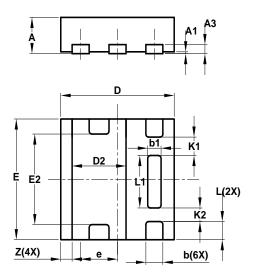
Fig. 10 Typical Drain-Source Leakage Current vs. Voltage





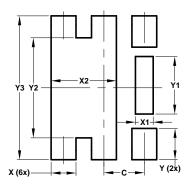


# **Package Outline Dimensions**



U-DFN2020-6								
Type E								
Dim	m Min Max Typ							
Α	0.57	0.63	0.60					
A1	0	0.05	0.03					
А3	_	_	0.15					
b	0.25	0.35	0.30					
b1	0.185	0.285	0.235					
D	1.95	2.05	2.00					
D2	0.85	1.05	0.95					
Е	1.95	2.05	2.00					
E2	1.40	1.60	1.50					
е	_	_	0.65					
L	0.25	0.35	0.30					
L1	0.82	0.92	0.87					
K1	_	_	0.305					
K2	_	_	0.225					
Z	_	_	0.20					
All Dimensions in mm								

## **Suggested Pad Layout**



Dimensions	Value		
Dillielisiolis	(in mm)		
С	0.650		
Х	0.400		
X1	0.285		
X2	1.050		
Υ	0.500		
Y1	0.920		
Y2	1.600		
Y3	2.300		



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